

CY7C1010DV33

2-Mbit (256K x 8) Static RAM

Features

- Pin and function compatible with CY7C1010CV33
- High speed □ t_{AA} = 10 ns
- Low active power □ I_{CC} = 90 mA at 10 ns
- Low CMOS standby power
 I_{SB2} = 10 mA
- 2.0V data retention
- Automatic power down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with CE and OE features
- Available in Pb-Free 36-pin SOJ and 44-pin TSOP II packages

Functional Description

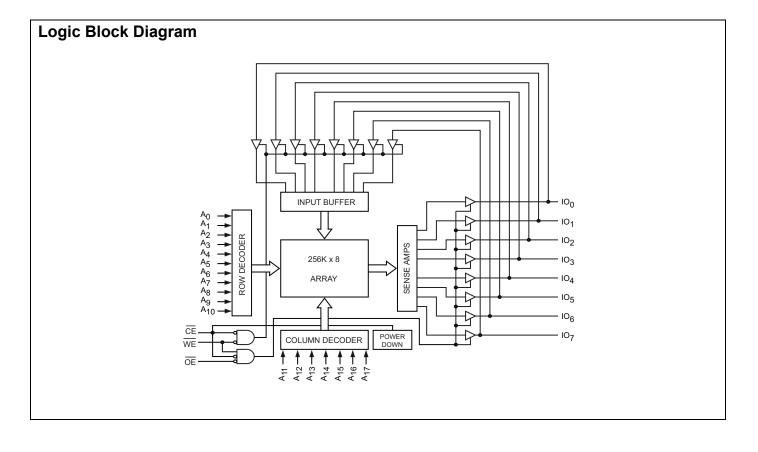
The CY7C1010DV33 is a high performance CMOS Static RAM organized as 256K words by 8 bits. Easy memory expansion is provided by an active LOW Chip Enable (\overline{CE}), an active LOW Output Enable (\overline{OE}), and three-state drivers. Writing to the device is accomplished by taking Chip Enable (\overline{CE}) and Write Enable (\overline{WE}) inputs LOW. Data on the eight I/O pins (I/O₀ through I/O₇) is then written into the location specified on the address pins (A₀ through A₁₇).

<u>Rea</u>ding from the device is <u>ac</u>complished by taking Chip Enable (\overline{CE}) and Output Enable (\overline{OE}) LOW while forcing Write Enable (WE) HIGH. Under these conditions, the contents of the memory location specified by the address pins will appear on the I/O pins.

The eight input and output pins $(I/O_0 \text{ through } I/O_7)$ are placed in a high impedance state when the device is deselected (CE HIGH), the outputs are disabled (OE HIGH), or during a Write operation (CE LOW, and WE LOW).

The CY7C1010DV33 is available in 36-pin SOJ and 44-pin TSOP II packages with center power and ground (revolutionary) pinout.

Refer to the Cypress application note AN1064, SRAM System Guidelines for best practice recommendations.



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Selection Guide

Description	-10	Unit
Maximum Access Time	10	ns
Maximum Operating Current	90	mA
Maximum CMOS Standby Current	10	mA

Pin Configuration

Figure 1. 36-Pin SOJ^[1]

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	5 5 3 E 7 6 ND 5 4 9 10 11 2 C
--	---

Figure 2. 44-Pin TSOP II [1]

$\begin{array}{c} \square \square$	0 1 2 3 4 5 6 7 8 9 10 11 12 13	44 43 42 41 40 39 38 37 36 35 34 33 32		NC NC $A_5 = A_6 A_7 A_8 O O O O O O O O O O O O O O O O O O O$
	•		E	
	9		Б	10 ₇
	10	35		10 ₆
V _{CC} □	11	34		V_{SS}
V _{SS} □	12	33		
$IO_2 \square$	13	32		IO_5
IO ₃	14	31		IO_4
WE L	15	30		A ₉
A ₁₇ □	16	29		A ₁₀
A ₁₆ □	17	28		A ₁₁
A ₁₅ □	18	27		A ₁₂
A ₁₄ □	19	26		NC
A ₁₃ □	20	25	Ρ	NC
NC 🗆	21	24		NC
№ Ц	22	23	Р	NC



Maximum Ratings

Exceeding the maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied –55°C to +125°C
Supply Voltage on V _{CC} Relative to GND $^{[2]} \hdots -0.5 V$ to +4.6V
DC Voltage Applied to Outputs
DC Voltage Applied to Outputs in High Z State $^{[2]}$ 0.3V to V_{CC} + 0.3V
DC Input Voltage $^{[2]}\ldots\ldots -0.3V$ to V_{CC} + 0.3V

Current into Outputs (LOW)	20 mA
Static Discharge Voltage	>2001V
(MIL-STD-883, Method 3015)	
Latch Up Current	>200 mA

Operating Range

Range	Ambient Temperature	V _{cc}
Industrial	–40°C to +85°C	$3.3V\pm0.3V$

Electrical Characteristics

Over the Operating Range

		Test Conditions		-10		
Parameter	Description			Min	Max	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = Min.; I _{OH} = -4.0 mA	۹.	2.4		V
V _{OL}	Output LOW Voltage	V _{CC} = Min.; I _{OL} = 8.0 mA			0.4	V
V _{IH}	Input HIGH Voltage			2.0	V _{CC} + 0.3	V
V _{IL}	Input LOW Voltage ^[2]			-0.3	0.8	V
I _{IX}	Input Leakage Current	$GND \leq V_I \leq V_{CC}$		-1	+1	μA
I _{OZ}	Output Leakage Current	$GND \leq V_{OUT} \leq V_{CC}$, Output	ut Disabled	-1	+1	μA
I _{CC}	V _{CC} Operating Supply Current	V _{CC} = Max.,	100 MHz		90	mA
		$f = f_{MAX} = 1/t_{RC}$	83 MHz		80	
			66 MHz		70	
			40 MHz		60	
I _{SB1}	Automatic CE Power-down Current —TTL Inputs	$\begin{array}{l} \text{Max. } V_{CC}, \ \overline{CE} \geq V_{IH}; \ V_{IN} \geq \\ V_{IN} \leq V_{IL}, \ f = f_{MAX} \end{array}$	V _{IH} or		20	mA
I _{SB2}	Automatic CE Power-down Current —CMOS Inputs	Max. V_{CC} , $\overline{CE} \ge V_{CC} - 0.3$ $V_{IN} \ge V_{CC} - 0.3$ V, or $V_{IN} \le$			10	mA

Capacitance

Tested initially and after any design or process changes that may affect these parameters.

Parameter	Description	Test Conditions	SOJ	TSOP II	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz}, V_{CC} = 3.3V$	8	8	pF
C _{OUT}	IO Capacitance		8	8	pF

Thermal Resistance

Tested initially and after any design or process changes that may affect these parameters.

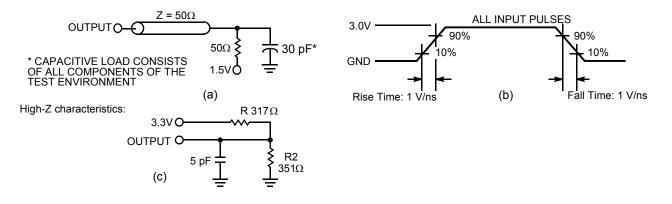
Parameter	Description	Test Conditions	SOJ	TSOP II	Unit
Θ_{JA}	Thermal Resistance (Junction to Ambient)	Still air, soldered on a 3 × 4.5 inch, four layer printed circuit board	59.17	50.66	°C/W
Θ _{JC}	Thermal Resistance (Junction to Case)		32.63	17.77	°C/W

Note

2. V_{IL} (min.) = -2.0V and V_{IH} (max.) = V_{CC} + 2.0V for pulse durations of less than 20 ns.







Note

AC characteristics (except High-Z) are tested using the load conditions shown in Figure (a). High-Z characteristics are tested for all speeds using the test load shown in Figure (c).



AC Switching Characteristics

Over the Operating Range^[4]

		-1	0	
Parameter	Description	Min.	Max.	Unit
Read Cycle				
t _{power} [5]	V _{CC} (typical) to the first access	100		μS
t _{RC}	Read Cycle Time	10		ns
t _{AA}	Address to Data Valid		10	ns
t _{OHA}	Data Hold from Address Change	3		ns
t _{ACE}	CE LOW to Data Valid		10	ns
t _{DOE}	OE LOW to Data Valid		5	ns
t _{LZOE}	OE LOW to Low-Z	0		ns
t _{HZOE}	OE HIGH to High-Z ^[6, 7]		5	ns
t _{LZCE}	CE LOW to Low-Z ^[7]	3		ns
t _{HZCE}	CE HIGH to High-Z ^[6, 7]		5	ns
t _{PU}	CE LOW to Power-up	0		ns
t _{PD}	CE HIGH to Power-down		10	ns
Write Cycle ^[8, 9]				
t _{WC}	Write Cycle Time	10		ns
t _{SCE}	CE LOW to Write End	7		ns
t _{AW}	Address Set-up to Write End	7		ns
t _{HA}	Address Hold from Write End	0		ns
t _{SA}	Address Set-up to Write Start	0		ns
t _{PWE}	WE Pulse Width	7		ns
t _{SD}	Data Set-up to Write End	5		ns
t _{HD}	Data Hold from Write End	0		ns
t _{LZWE}	WE HIGH to Low-Z ^[7]	3		ns
t _{HZWE}	WE LOW to High-Z ^[6, 7]		5	ns

Notes:

4. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V.

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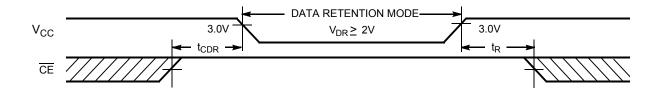


Data Retention Characteristics

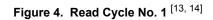
Over the Operating Range ^[10]

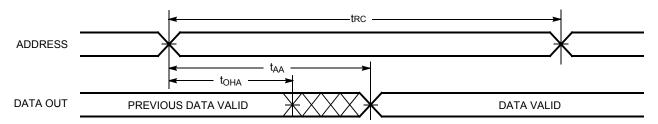
Parameter	Description	Conditions	Min	Мах	Unit
V _{DR}	V _{CC} for Data Retention		2		V
I _{CCDR}	Data Retention Current	$V_{CC} = V_{DR} = 2.0V, \overline{CE} \ge V_{CC} - 0.3V,$ $V_{IN} \ge V_{CC} - 0.3V \text{ or } V_{IN} \le 0.3V$		10	mA
t _{CDR} ^[11]	Chip Deselect to Data Retention Time		0		ns
t _R ^[12]	Operation Recovery Time		t _{RC}		ns

Data Retention Waveform



Switching Waveforms





Notes

- 10. No inputs may exceed V_{CC} + 0.3V 11. Tested initially and after any design or process changes that may affect these parameters. 12. Full device operation requires linear V_{CC} ramp from V_{DR} to V_{CC(min.)} \geq 50 µs or stable at V_{CC(min.)} \geq 50 µs. 13. The device is continuously selected. OE, $\overline{CE} = V_{IL}$. 14. WE is HIGH for read cycle.



Switching Waveforms (continued)

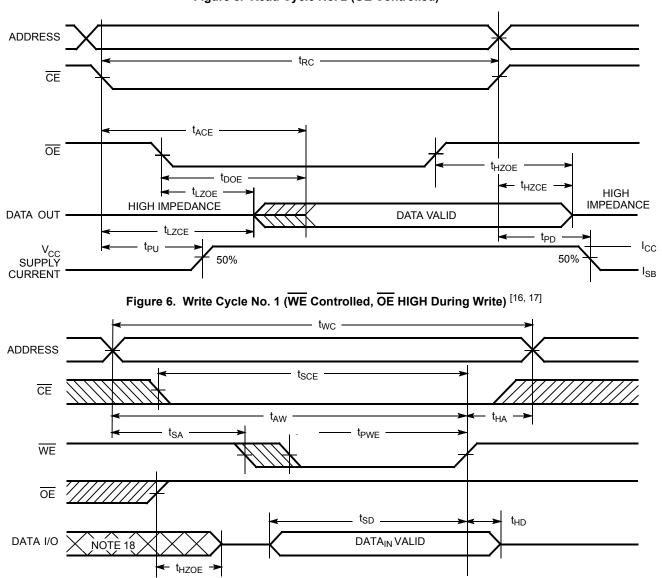


Figure 5. Read Cycle No. 2 (OE Controlled) ^[14, 15]

Notes

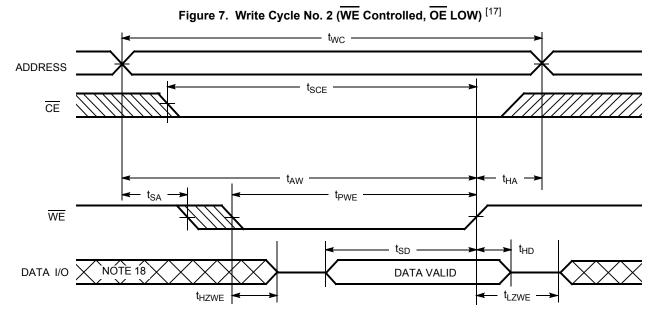
15. Address valid before or similar to CE transition LOW.

16. Data IO is high impedance if $\overline{OE} = V_{IH}$. 17. If \overline{OE} goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.

18. During this period, the I/Os are in output state and input signals should not be applied.



Switching Waveforms (continued)



Truth Table

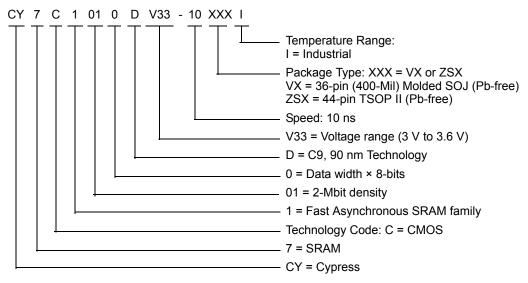
CE	OE	WE	10 ₀ –10 ₇	10 ₈ –10 ₁₅	Mode	Power
Н	Х	Х	High-Z	High-Z	Power Down	Standby (I _{SB})
L	L	Н	Data Out	Data Out	Read All Bits	Active (I _{CC})
L	Х	L	Data In	Data In	Write All Bits	Active (I _{CC})
L	Н	Н	High-Z	High-Z	Selected, Outputs Disabled	Active (I _{CC})



Ordering Information

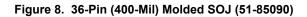
Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C1010DV33-10VXI	51-85090	36-pin (400-Mil) Molded SOJ (Pb-free)	Industrial
	CY7C1010DV33-10ZSXI	51-85087	44-pin TSOP II (Pb-free)	

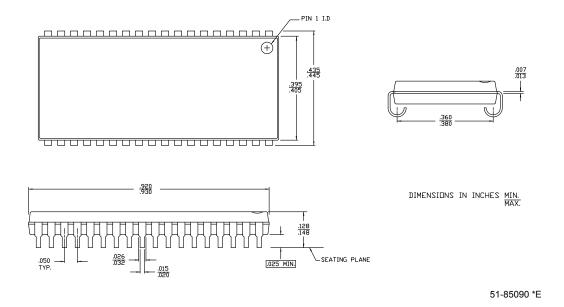
Ordering Code Definitions





Package Diagrams

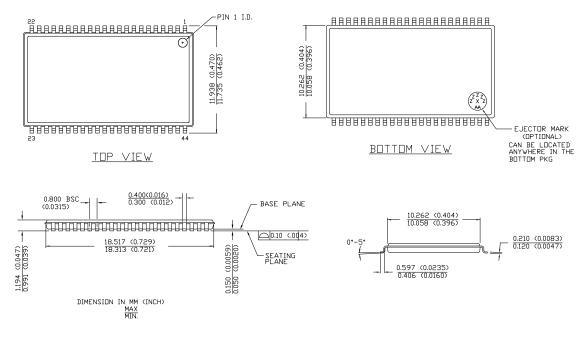






Package Diagrams (continued)





51-85087 *C



Document History Page

Document Title: CY7C1010DV33, 2-Mbit (256K x 8) Static RAM Document Number: 001-00062							
REV.	ECN NO.	Submission Date	Orig. of Change	Description of Change			
**	342195	See ECN	PCI	New Data sheet			
*A	459073	See ECN	NXR	Converted Preliminary to Final. Removed Commercial Operating Range from product offering. Removed -8 ns and -12 speed bin Removed the Pin definitions table. Modified Maximum Ratings for DC input voltage from -0.5V to -0.3V and V_{CC} + 0.5V to V_{CC} + 0.3V Changed I _{CC} max from 65 mA to 90 mA Changed the description of I _{IX} from "Input Load Current" to "Input Leakage Current" Updated the Thermal Resistance table. Updated footnote #7 on High-Z parameter measurement Added footnote #12 Updated the Ordering Information and replaced Package Name column with Package Diagram in the Ordering Information table.			
*B	2602853	11/07/08	VKN/PYRS	Added 36-pin SOJ package and its related information			
*C	3059211	10/14/2010	PRAS	Added Ordering Code Definitions. Updated Package Diagrams.			

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